

Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) [1] @ 10mA		Description
			Min.	Typ.	
PDA54-12SYKWA	Super Bright Yellow (AlGaInP)	White Diffused	21000	46000	Common Anode, Rt. Hand Decimal

Note:

1. Luminous intensity/ luminous Flux: +/-15%.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	Super Bright Yellow	590		nm	I _F =20mA
λ_D [1]	Dominant Wavelength	Super Bright Yellow	590		nm	I _F =20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	Super Bright Yellow	20		nm	I _F =20mA
C	Capacitance	Super Bright Yellow	20		pF	V _F =0V;f=1MHz
V _F [2]	Forward Voltage Per Segment or DP	Super Bright Yellow	2.0	2.5	V	I _F =20mA
I _R	Reverse Current Per Segment or DP	Super Bright Yellow		10	uA	V _R =5V

Notes:

1. Wavelength: +/-1nm.

2. Forward Voltage: +/-0.1V.

Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Yellow	Units
Power dissipation Per Segment or DP	75	mW
DC Forward Current Per Segment or DP	30	mA
Peak Forward Current [1] Per Segment or DP	175	mA
Reverse Voltage Per Segment or DP	5	V
Operating / Storage Temperature	-40°C To +85°C	
Lead Solder Temperature[2]	260°C For 3-5 Seconds	

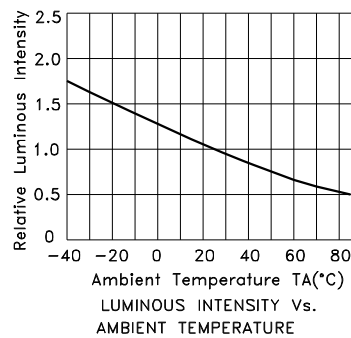
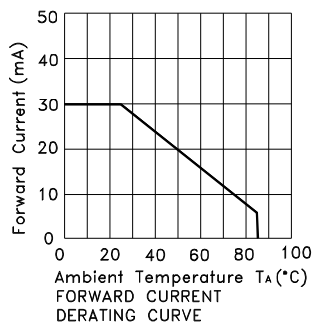
Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

2. 2mm below package base.

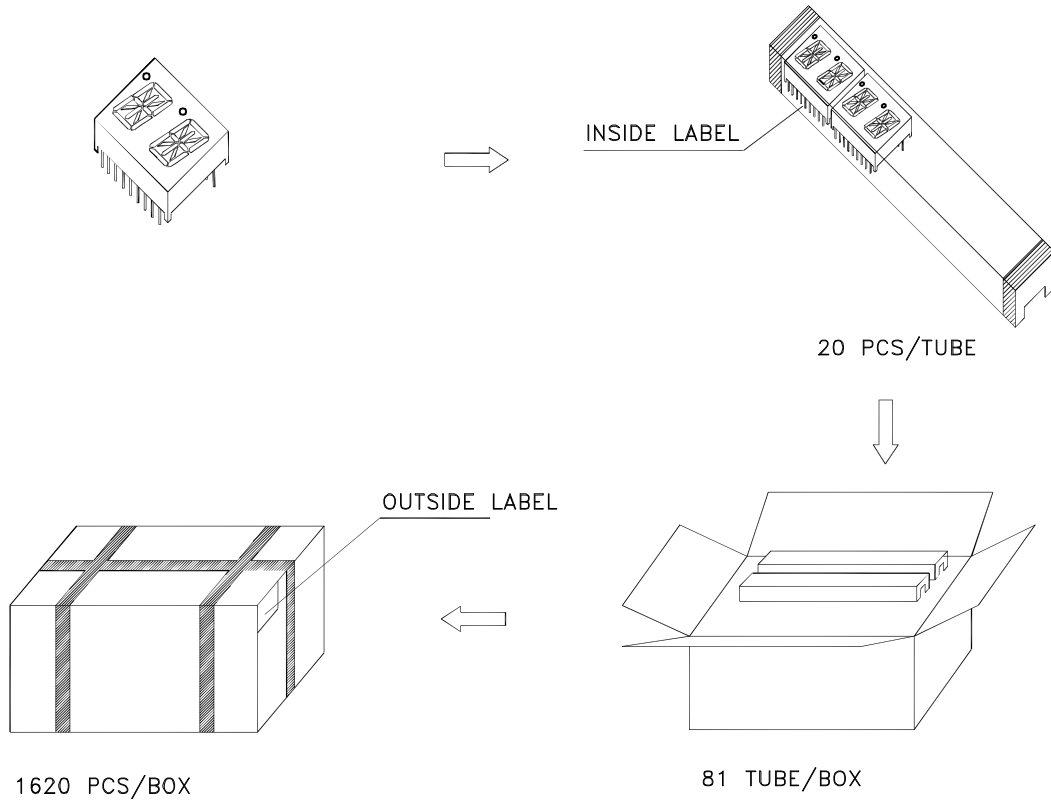


Super Bright Yellow PDA54-12SYKWA

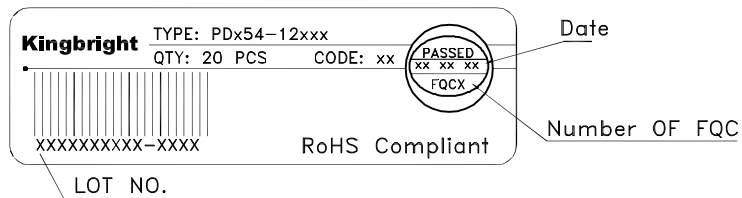


PACKING & LABEL SPECIFICATIONS

PDA54-12SYKWA



Inside Label On IC-tube



Outside Label On Box

